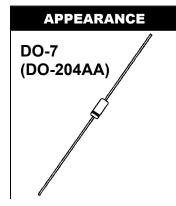


#### 1N935 thru 1N940B-1

9.0 Volt Temperature Compensated Zener Reference Diodes

#### DESCRIPTION

The popular 1N935 thru 1N940B series of Zero-TC Reference Diodes provides a selection of 9.0 V nominal voltages and temperature coefficients to as low as 0.0002%/°C for minimal voltage change with temperature when operated at 7.5 mA. These glass axial-leaded DO-7 reference diodes are also available in JAN, JANTX, and JANTXV military qualifications. Microsemi also offers numerous other Zener Reference Diode products for a variety of other voltages from 6.2 V to 200 V.



IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

#### **FEATURES**

- JEDEC registered 1N935 thru 1N940 series
- Standard reference voltage of 9.0V +/- 5%
- 1N935B, 937B, 938B, 939B, 940B also have military qualification to MIL-PRF-19500/156 up to the JANTXV level by adding JAN, JANTX, or JANTXV prefixes to part numbers as well as "-1" suffix, e.g. JANTX1N938B-1, etc.
- Internal metallurgical bonds
- · JANS Equivalent available via SCD
- Radiation Hardened devices available by changing "1N" prefix to "RH", e.g. RH938B, RH 940B, etc.
  Also consult factory for "RH" data sheet brochure

#### **APPLICATIONS / BENEFITS**

- Provides minimal voltage changes over a broad temperature range
- For instrumentation and other circuit designs requiring a stable voltage reference
- Maximum temperature coefficient selections available from 0.01%/°C to 0.0002%/°C
- Tight voltage tolerances available with nominal voltage of 9.2 V by adding tolerance 1%, 2%, 3%, etc. after the part number for further identification, e.g. 1N938B-2%, 1N940B-1%, 1N939B-1-1%, etc.
- Flexible axial-leaded mounting terminals
- Nonsensitive to ESD per MIL-STD-750 Method 1020

#### **MAXIMUM RATINGS**

- Operating & StorageTemperature: -65°C to +175°C
- DC Power Dissipation: 500 mW @ T<sub>L</sub> = 25°C and maximum current I<sub>ZM</sub> of 50 mA. NOTE: For optimum voltage-temperature stability, I<sub>Z</sub> = 7.5 mA (less than 75 mW in dissipated power)
- Solder temperatures: 260 °C for 10 s (maximum)

#### **MECHANICAL AND PACKAGING**

- CASE: Hermetically sealed glass case with DO-7 (DO-204AA) package
- TERMINALS: Tin-lead plated and solderable per MIL-STD-750, Method 2026
- MARKING: Part number and cathode band
- POLARITY: Reference diode to be operated with the banded end positive with respect to the opposite end
- TAPE & REEL option: Standard per EIA-296 (add "TR" suffix to part number)
- WEIGHT: 0.2 grams.
- See package dimensions on last page

# **Microsemi**

SCOTTSDALE DIVISION

#### 1N935 thru 1N940B-1

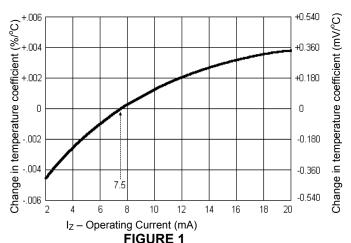
#### 9.0 Volt Temperature Compensated Zener Reference Diodes

#### \*ELECTRICAL CHARACTERISTICS @ 25°C, unless otherwise specified VOLTAGE ZENER **MAXIMUM** ZENER MAXIMUM TEMPERATURE **EFFECTIVE JEDEC** VOLTAGE ZENER **TEST REVERSE STABILITY TEMPERATURE TEMPERATURE TYPE IMPEDANCE** Vz@IzT CURRENT **RANGE** COEFFICIENT **CURRENT** (Notes 3 & 4) **NUMBERS** (Notes (Note 2) I<sub>R</sub> @ 6 V $\Lambda V_{7T}$ (Notes Iт $\alpha_{vz}$ 1, 4 & 5) Z<sub>ZT</sub> @ I<sub>ZT</sub> **MAXIMUM** 1 & 5) °C %/°C **VOLTS OHMS** mA m۷ μΑ 0 to +75 1N935 8.55-9.45 7.5 20 10 67 0.01 1N935A 8.55-9.45 7.5 20 10 139 -55 to +100 0.01 1N935B 8.55-9.45 -55 to +150 7.5 20 10 184 0.01 1N936 8.55-9.45 7.5 20 10 33 0 to +75 0.005 1N936A 8.55-9.45 7.5 20 10 69 -55 to +100 0.005 1N936B 8.55-9.45 -55 to +150 0.005 7.5 20 10 92 7.5 0 to +75 1N937 8.55-9.45 20 10 13 0.002 1N937A 27 -55 to +100 8.55-9.45 7.5 20 10 0.002 1N937B 8.55-9.45 7.5 20 10 37 -55 to +150 0.002 1N938 8.55-9.45 7.5 20 10 6 0 to +75 0.001 1N938A 8.55-9.45 -55 to +100 0.001 7.5 20 10 13 1N938B 8.55-9.45 -55 to +150 0.001 7.5 20 10 18 8.55-9.45 3 0 to +75 0.0005 1N939 7.5 20 10 1N939A 8.55-9.45 7.5 20 10 7 -55 to +100 0.0005 1N939B 8.55-9.45 7.5 20 10 9 -55 to +150 0.0005 1N940 8.55-9.45 7.5 20 1.3 0 to +75 0.0002 10 1N940A 8.55-9.45 7.5 20 10 2.7 -55 to +100 0.0002 1N940B 8.55-9.45 7.5 20 10 3.7 -55 to +150 0.0002

#### **NOTES:**

- 1. When ordering devices with tighter tolerances than specified, use a nominal voltage of 9.2V and add a hyphenated suffix to the part number for desired tolerance at the end of the part number, e.g. 1N938B-2%, 1N939B-1%, 1N939B-1-1%, etc.
- Measured by superimposing 0.75 mA ac rms on 7.5 mA dc @ 25°C.
- 3. The maximum allowable change observed over the entire temperature range i.e., the diode voltage will not exceed the specified mV change at any discrete temperature between the established limits.
- 4. Voltage measurements to be performed 15 seconds after application of dc current.
- 5. The 1N935B, 937B, 938B, 939B, 940B also have military qualification to MIL-PRF-19500/156 up to the JANTXV level by adding JAN, JANTX, or JANTXV prefixes to part numbers as well as "-1" suffix, e.g. JANTX1N938B-1, etc.
- Designate Radiation Hardened devices with "RH" prefix instead of "IN", i.e. RH938A instead of 1N938A.

#### **GRAPHS**



The curve shown in Figure 1 is typical of the diode series and greatly simplifies the estimation of the Temperature Coefficient (TC) when the diode is operated at currents other than 7.5mA.

EXAMPLE: A diode in this series is operated at a current of 7.5mA and has specified Temperature Coefficient (TC) limits of +/-0.005%/°C. To obtain the typical Temperature Coefficient limits for this same diode operated at a current of 6.0mA, the new TC limits (%°C) can be estimated using the graph in FIGURE 1.

At a test current of 6.0mA the change in Temperature Coefficient (TC) is approximately -0.0009%.°C. The algebraic sum of +/-0.005%°C and -0.0009%,°C gives the new estimated limits of +0.0041%/oC and -0.0059%/oC.

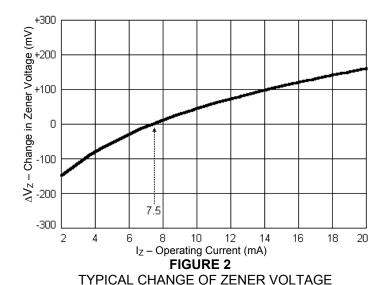
TYPICAL CHANGE OF TEMPERATURE COEFFICIENT WITH CHANGE IN OPERATING CURRENT.

<sup>\*</sup>JEDEC Registered Data.



#### 1N935 thru 1N940B-1

## 9.0 Volt Temperature Compensated Zener Reference Diodes

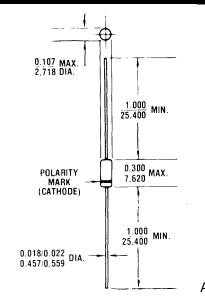


WITH CHANGE IN OPERATING CURRENT.

This curve in Figure 2 illustrates the change of diode voltage arising from the effect of impedance. It is in effect an exploded view of the zener operating region of the I-V characteristic.

In conjunction with Figure 1, this curve can be used to estimate total voltage regulation under conditions of both varying temperature and current.

### DIMENSIONS



All dimensions in INCH mm

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.